NSN 5961-00-729-3395



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-00-729-3395 **Inclosure Material:** Metal **Overall Length:** Between 0.240 inches and 0.260 inches **Terminal Length:** 1.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-5 **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Npn **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 15.0 breakdown voltage, collector-to-base, emitter open and 15.0 breakdown voltage, collector-to-emitter, base open and 3.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 100.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release3419 professional/industrial association specification Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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